SGDS015 - FEBRUARY 2002

- **Q Devices Meet Automotive Performance** Requirements
- **Customer-Specific Configuration Control** Can Be Supported Along With **Major-Change Approval**
- **EPIC™** (Enhanced-Performance Implanted **CMOS) Process**
- Operating Range 2-V to 5.5-V V_{CC}
- Latch-Up Performance Exceeds 250 mA Per

DOR PW PACKAGE (TOP VIEW) 1OF 14 🛮 V_{CC} 1A [2 13 40E 1Y [3 12 4A 2ΟΕ Π 11 ¶ 4Y 10 ¶ 30E 2A 5 2Y 6 9 🛮 3A **GND** 8**∏** 3Y

description

The SN74AHC125Q is a guadruple bus buffer gate featuring independent line drivers with 3-state outputs. Each output is disabled when the associated output-enable (\overline{OE}) input is high. When \overline{OE} is low, the respective gate passes the data from the A input to its Y output.

To ensure the high-impedance state during power up or power down, OE should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

ORDERING INFORMATION

T _A	PACK	AGE [†]	ORDERABLE PART NUMBER	TOP-SIDE MARKING
4000 to 40500	SOIC - D	Tape and reel	SN74AHC125QDR	AHC125Q
-40°C to 125°C	TSSOP – PW	Tape and reel	SN74AHC125QPWR	HA125Q

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE (each buffer)

INPU	JTS	OUTPUT
OE	Α	Υ
L	Н	Н
L	L	L
Н	Χ	Z

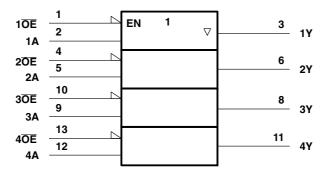


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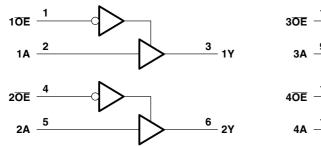


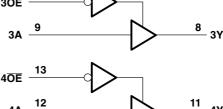
logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)





absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[‡]

Supply voltage range, V _{CC}	–0.5 V to 7 V
Input voltage range, V _I (see Note 1)	–0.5 V to 7 V
Output voltage range, V _O (see Note 1)	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, I _{IK} (V _I < 0)	–20 mA
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CC})	±20 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})	±25 mA
Continuous current through V _{CC} or GND	±50 mA
Package thermal impedance, θ_{JA} (see Note 2): D package	86°C/W
PW package	113°C/W
Storage temperature range, T _{stg}	–65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51-7.



recommended operating conditions (see Note 3)

			MIN	MAX	UNIT
V_{CC}	Supply voltage		2	5.5	V
		V _{CC} = 2 V	1.5		
V_{IH}	High-level input voltage Low-level input voltage Input voltage Output voltage High-level output current	V _{CC} = 3 V	2.1		V
		V _{CC} = 5.5 V	3.85		
		V _{CC} = 2 V		0.5	
V_{IL}	Low-level input voltage V _{CC} = 3 V			0.9	V
		V _{CC} = 5.5 V		1.65	
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	V_{CC}	V
		V _{CC} = 2 V		-50	μΑ
I _{OH}	High-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		-4	
	O Output voltage OH High-level output current	$V_{CC} = 5 V \pm 0.5 V$		-8	mA
		V _{CC} = 2 V		50	μΑ
I_{OL}	Low-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		4	
		$V_{CC} = 5 V \pm 0.5 V$		8	mA
44/4	hand han although a sufall ask.	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		100	
ΔυΔν	input transition rise or fall rate	V_{CC} = 5 V \pm 0.5 V		20	ns/V
T _A	Operating free-air temperature		-40	125	°C

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

24244555	TEST COMPLETIONS	.,	T,	_A = 25°C	;		MAY		
PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	MIN	MAX	UNIT	
		2 V	1.9	2		1.9			
	$I_{OH} = -50 \mu A$	3 V	2.9	3		2.9			
V _{OH}		4.5 V	4.4	4.5		4.4		V	
	$I_{OH} = -4 \text{ mA}$	3 V	2.58			2.48			
	$I_{OH} = -8 \text{ mA}$	4.5 V	3.94			3.8			
		2 V			0.1		0.1		
	$I_{OL} = 50 \mu A$	3 V			0.1		0.1		
V _{OL}		4.5 V			0.1		0.1	V	
	I _{OL} = 4 mA	3 V			0.36		0.5		
	I _{OL} = 8 mA	4.5 V			0.36		0.5		
I _I	V _I = 5.5 V or GND	0 V to 5.5 V			±0.1		±1	μΑ	
loz	V _O = V _{CC} or GND	5.5 V			±0.25		±2.5	μΑ	
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		40	μΑ	
C _i	V _I = V _{CC} or GND	5 V		4	10			pF	

SN74AHC125Q QUADRUPLE BUS BUFFER GATE WITH 3-STATE OUTPUTS

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switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

DADAMETED	FROM	то	LOAD	T _A	= 25°C		MAINI	14 A V	
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	UNIT
t _{PLH}		Y	0 15 -5		5.6	8	1	9.5	
t _{PHL}	Α	Y	C _L = 15 pF		5.6	8	1	9.5	ns
t _{PZH}	<u> </u>	V	0 15 -5		5.4	8	1	9.5	
t _{PZL}	ŌĒ	Υ	C _L = 15 pF		5.4	8	1	9.5	ns
t _{PHZ}	<u> </u>	V	0 45 5		7	9.7	1	11.5	
t _{PLZ}	ŌĒ	Υ	C _L = 15 pF		7	9.7	1	11.5	ns
t _{PLH}		V	0 50 5		8.1	11.5	1	13	
t _{PHL}	Α	Υ	C _L = 50 pF		8.1	11.5	1	13	ns
t _{PZH}	~=	V	0 50 5		7.9	11.5	1	13	
t _{PZL}	ŌĒ	Υ	C _L = 50 pF		7.9	11.5	1	13	ns
t _{PHZ}	ŌĒ	Y	C - F0 pF		9.5	13.2	1	15	no
t _{PLZ}	OE .	ſ	C _L = 50 pF		9.5	13.2	1	15	ns

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

DADAMETED	FROM	то	LOAD	T,	λ = 25°C			MAY	
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	UNIT
t _{PLH}	•	V	0 455		3.8	5.5	1	6.5	
t _{PHL}	А	Υ	C _L = 15 pF		3.8	5.5	1	6.5	ns
t _{PZH}	\-	V	0 455		3.6	5.1	1	6	
t _{PZL}	ŌĒ	Υ	C _L = 15 pF		3.6	5.1	1	6	ns
t _{PHZ}		V	C _L = 15 pF		4.6	6.8	1	8	
t _{PLZ}	ŌĒ	Υ			4.6	6.8	1	8	ns
t _{PLH}	•	V	0 50 5		5.3	7.5	1	8.5	
t _{PHL}	Α	Υ	$C_L = 50 \text{ pF}$		5.3	7.5	1	8.5	ns
t _{PZH}	S.E.	.,	0 50 5		5.1	7.1	1	8	
t _{PZL}	ŌĒ	Υ	C _L = 50 pF		5.1	7.1	1	8	ns
t _{PHZ}	ŌĒ	Y	C: - F0 pF		6.1	8.8	1	10	no
t _{PLZ}	OE .	1	$C_L = 50 \text{ pF}$		6.1	8.8	1	10	ns

noise characteristics, $V_{CC} = 5 \text{ V}$, $C_L = 50 \text{ pF}$, $T_A = 25^{\circ}\text{C}$ (see Note 4)

	PARAMETER	MIN	MAX	UNIT
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		8.0	V
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}		-0.8	V
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}	4.4		V
V _{IH(D)}	High-level dynamic input voltage	3.5		V
$V_{IL(D)}$	Low-level dynamic input voltage		1.5	V

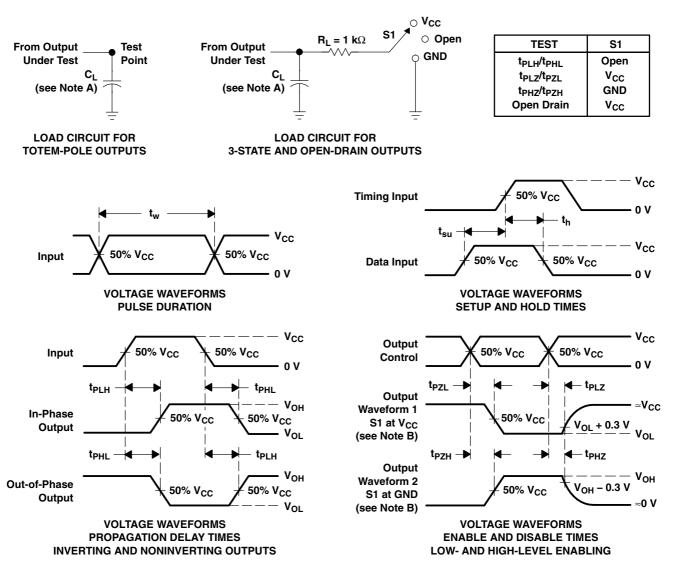
NOTE 4: Characteristics are for surface-mount packages only.

operating characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

	PARAMETER	TEST CO	NDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	No load,	f = 1 MHz	14	pF



PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_f \leq$ 3 ns, $t_f \leq$ 3 ns.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms







17-Oct-2011

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
SN74AHC125QDR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74AHC125QDRG4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74AHC125QPWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74AHC125QPWRG4	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE MATERIALS INFORMATION

14-Jul-2012 www.ti.com

TAPE AND REEL INFORMATION

REEL DIMENSIONS





TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHC125QPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

PACKAGE MATERIALS INFORMATION

www.ti.com 14-Jul-2012



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHC125QPWR	TSSOP	PW	14	2000	367.0	367.0	35.0

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
 - Sody length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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